



BCX5216Q / BCX5316Q

PNP MEDIUM POWER TRANSISTORS IN SOT89

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEO} > -60V & -80V
- I_C = -1A Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -500mV @ -0.5A
- Complementary NPN Type: BCX5616Q
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The BCX5216Q and BCX5316Q are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

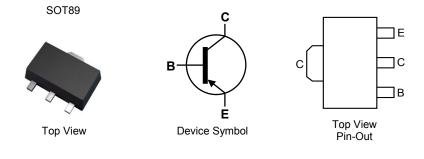
https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 Terminals: Finish - Matte Tin Finish Leads.
- Solderable per MIL-STD-202 Method 208 @3
- Weight: 0.055 grams (Approximate)

Applications

- Automotive Applications
- Medium Power Switching or Amplification Applications
- AF Drivers and Output Stages



Ordering Information (Note 4)

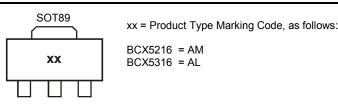
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCX5216QTA	Automotive	AM	7	12	1,000
BCX5216QTC	Automotive	AM	13	12	4,000
BCX5316QTA	Automotive	AL	7	12	1,000
BCX5316QTC	Automotive	AL	13	12	4,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information





Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX5216	BCX5316	Unit	
Collector-Base Voltage	V _{CBO}	-60	-100	V	
Collector-Emitter Voltage	V _{CEO}	-60	-80	V	
Emitter-Base Voltage	V _{EBO}	-	-5	V	
Continuous Collector Current	lc	-	·1		
Peak Pulse Collector Current (Single Pulse)	I _{CM}		-2	A	
Continuous Base Current	Ι _Β	-1	00	mA	
Peak Pulse Base Current (Single Pulse)	I _{BM}	-2	200		

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	PD	1.5	W	
	(Note 7)		2.0		
	(Note 5)		125		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _{0JA}	83	°C/W	
	(Note 7)		60		
Thermal Resistance, Junction to Lead	(Note 8)	R _{θJL}	13	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 9)

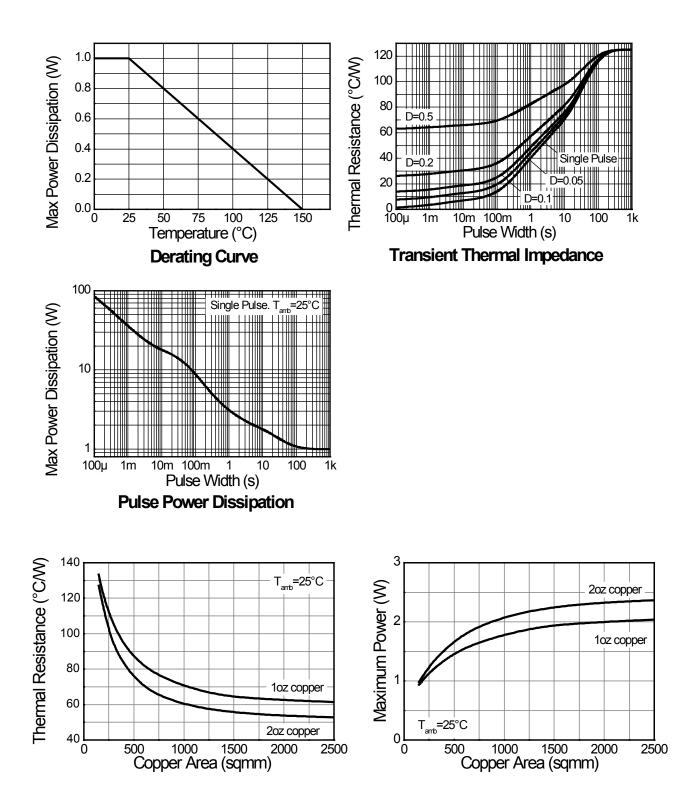
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conservice with the exposed contextor part of 15hill x 15hill 102 cc still air context with the exposed contextor part of 15hill x 15hill 102 cc still air context states.
Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

Same as Note 5, except the device is mounted on 20mm x 50mm 102 copper.
 Same as Note 5, except the device is mounted on 50mm x 50mm 102 copper.
 Thermal resistance from junction to solder-point (on the exposed collector pad).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



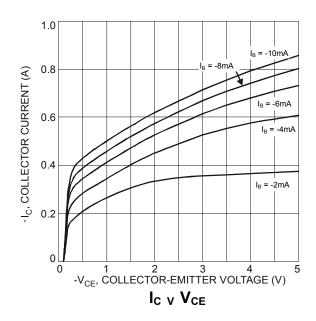


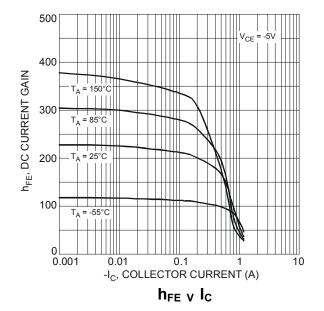
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base BCX5216		D\/ana	-60			V	I _C = -100µA
Breakdown Voltage	BCX5316	ВV _{CBO}	-100			v	IC = -100μΑ
Collector-Emitter	BCX5216	BV _{CEO}	-60	-	_	V	I _C = -10mA
Breakdown Voltage (Note 10)	BCX5316		-80				
Emitter-Base Breakdown Voltage		BV_{EBO}	-5	_	—	V	I _E = -10μΑ
Collector Cut-Off Current					-0.1		V _{CB} = -30V
Collector Cut-On Current		I _{CBO}	_	_	-20	μΑ	V_{CB} = -30V, T_{J} = +150°C
Emitter Cut-Off Current		I _{EBO}	-	_	-20	nA	V _{EB} = -5V
DC Current Gain (Note 10)			25	_	_		I _C = -5mA, V _{CE} = -2V
		h _{FE}	100	-	250	—	I _C = -150mA, V _{CE} = -2V
			25	-	-		I_{C} = -500mA, V_{CE} = -2V
Collector-Emitter Saturation Voltage (Note 10)		V _{CE(sat)}	-	_	-0.5	V	I _C = -500mA, I _B = -50mA
Base-Emitter Turn-On Voltage (Note 10)		V _{BE(on)}	_	—	-1.0	V	I _C = -500mA, V _{CE} = -2V
Transition frequency		f⊤	150		_	MHz	I _C = -50mA, V _{CE} = -10V f = 100MHz
Output Capacitance		Cobo	_	—	25	pF	V _{CB} = -10V, f = 1MHz

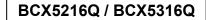
Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

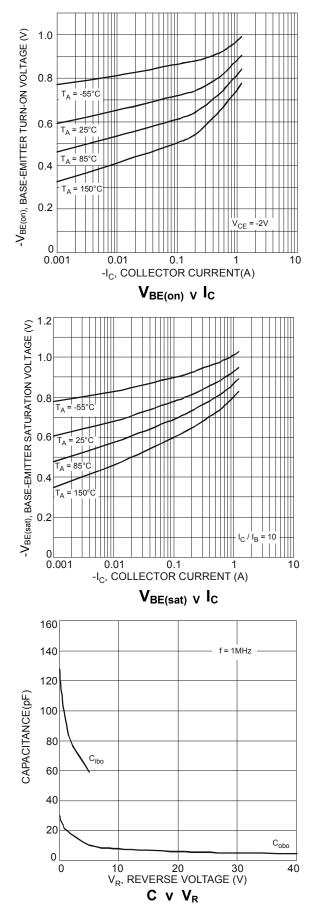
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

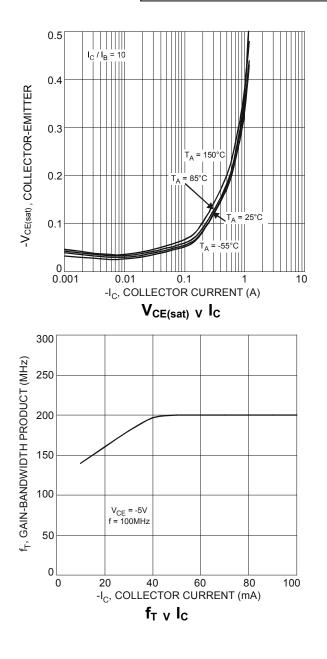








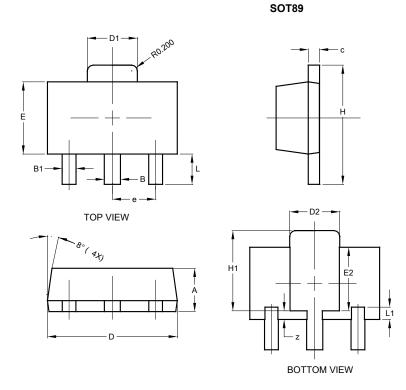






Package Outline Dimensions

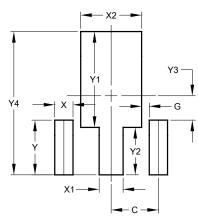
Please see http://www.diodes.com/package-outlines.html for the latest version.



1		700					
SOT89							
Dim	Min	Max	Тур				
Α	1.40	1.60	1.50				
В	0.50	0.62	0.56				
B1	0.42	0.54	0.48				
С	0.35	0.43	0.38				
D	4.40	4.60	4.50				
D1	1.62	1.83	1.733				
D2	1.61	1.81	1.71				
Е	2.40	2.60	2.50				
E2	2.05	2.35	2.20				
е	-	-	1.50				
Н	3.95	4.25	4.10				
H1	2.63	2.93	2.78				
L	0.90	1.20	1.05				
L1	0.327	0.527	0.427				
z	0.20	0.40	0.30				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value		
Dimensions	(in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Y	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		

SOT89



IMPORTANT NOTICE

1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5 products provided subject to Diodes' Standard Terms and Conditions of Sale Diodes are (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

Copyright © 2021 Diodes Incorporated

www.diodes.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))